

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Xuming Xiong, et al.

Title: BIAXIALY-TEXTURED FILM DEPOSITION FOR  
SUPERCONDUCTOR COATED TAPES

Application No.: 10/821,010

Filed: April 8, 2004

Examiner: UNASSIGNED

Group Art Unit: 1775

Atty. Docket No.: 1014-SP215

COMMISSIONER FOR PATENTS  
PO Box 1450  
Alexandria, VA 22313-1450

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Dear Sir:

Pursuant to 37 C.F.R. § 1.56, § 1.97 and § 1.98, the undersigned brings the patents, publications, applications or other information identified in the attached:

- ☒ Form(s) PTO/SB/08A and/or PTO/SB/08B or PTO/1449  
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to the Examiner's attention in the above-identified application. Citation of such information shall not be construed as:

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If the above-identified application is an original application filed on or after May 29, 2000:

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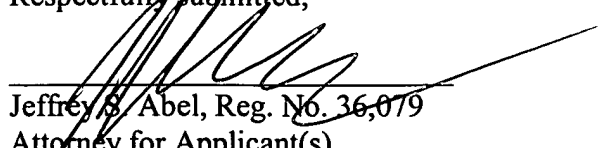
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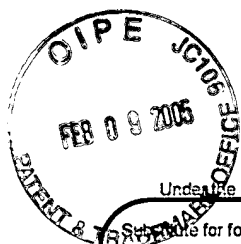
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Date

2/3/05

Respectfully submitted,

  
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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (Use as many sheets as necessary)		<b>Complete if Known</b>	
		Application Number	10/821,010
		Filing Date	April 8, 2004
		First Named Inventor	Xuming Xiong
		Art Unit	1775
		Examiner Name	Unassigned
Sheet 1	of 1	Attorney Docket Number	1014-SP215-US

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
	A	Y. Iijima, et al., "In-Plane Aligned YBa <sub>2</sub> Cu <sub>3</sub> O <sub>7-x</sub> Thin Films Deposited on Polycrystalline Metallic Substrates", Appl. Phys. Letters, Vol. 60, pp. 769-771, 1992.	
	B	X. Wu, et al., "Properties of YBa <sub>2</sub> Cu <sub>3</sub> O <sub>7-s</sub> Thick Films on Flexible Buffered Metallic Substrates", Appl. Phys. Letters, Vol. 67, No. 16, pp. 2397-2399, 1995.	
	C	H. Freyhardt, et al., "YBaCuO Thick Films on Planar and Curved Technical Substrates", Vol. 7, No. 2, pp. 1426-1431, 1997.	
	D	R. Huehne, et al., "Growth of Biaxial Textured MgO-Layers by Ion-Beam Assisted Pulsed Laser Deposition", Crystal Res. Technology, Vol. 35, No. 4, pp. 419-425, 2000.	
	E	L. Dong, et al., "Texture Development Mechanisms in Ion Beam Assisted Deposition", Journal of Applied Physics, Vol. 84, No. 9, pp. 5261-5269, 1998.	
	F	J. Groves, et al., "Recent Progress in Continuously Processes IBAD MgO Template Meters for HTS Applications, Physica C 382, pp. 43-47, 2002.	
	G		
	H		
	I		
	J		

Examiner Signature	Date Considered
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